

# **MMBT5551**

## **DATASHEET**

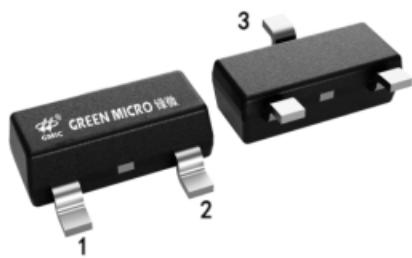
### **Specification Revision History:**

Version	Date	Description
V1.0	2021/04	New
V1.1	2022/03	Modify Ordering Information
V1.2	2024/02	Modify Ordering Information
V1.3	2025/05	Add application precautions and overall typesetting.

## Features

- ※NPN Transistors
- ※High Voltage Transistors
- ※Pb-Free Packages are Available

## Simplified outline



- 1.Base
- 2.Emitter
- 3.Collector

SOT-23

## Ordering Information

Product Model	Package Type	Marking	Packing	Packing Qty
MMBT5551-GM	SOT-23	G1	REEL	3000PCS/REEL

## Absolute Maximum Ratings $T_a = 25 \text{ }^{\circ}\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	180	V
Collector-emitter voltage	$V_{CEO}$	160	V
Emitter-base voltage	$V_{EBO}$	6	V
Collector current-continuous	$I_C$	0.6	
Collector Power Dissipation	$P_C$	350	mW
Junction and storage temperature	$T_J, T_{stg}$	-55 to +150	$^{\circ}\text{C}$

## Electrical Characteristics $T_a = 25 \text{ } ^\circ\text{C}$

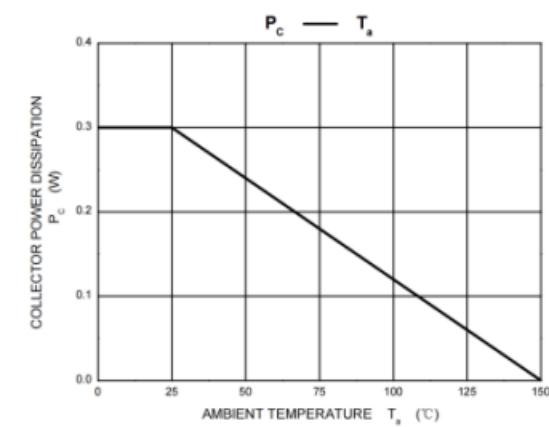
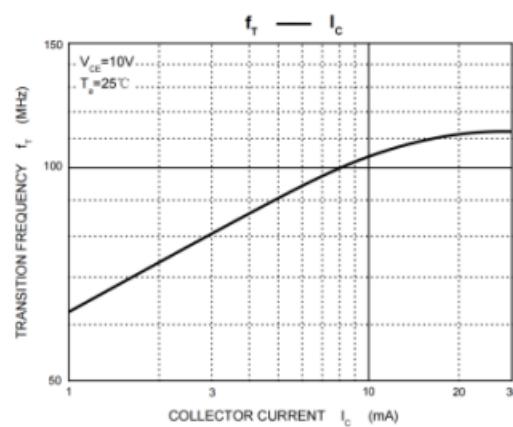
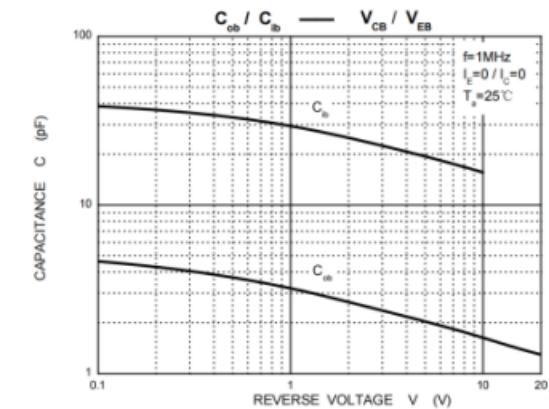
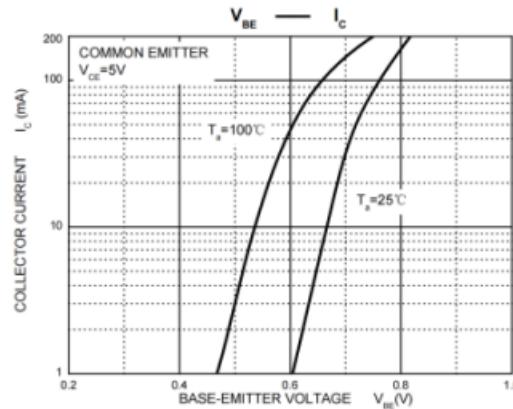
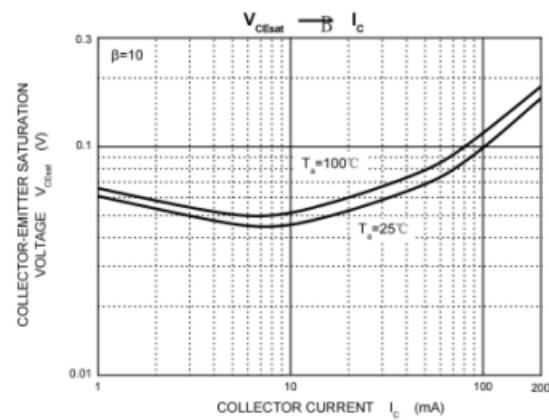
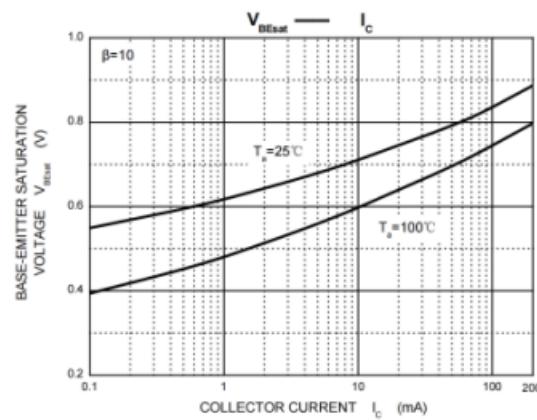
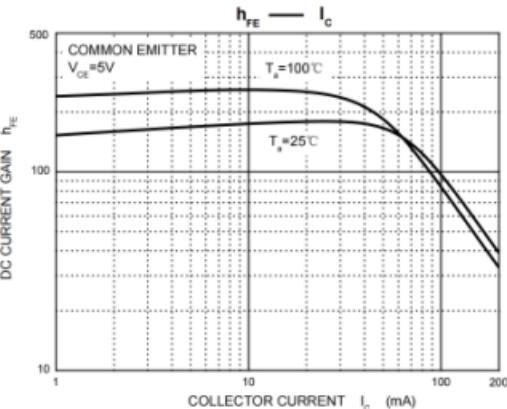
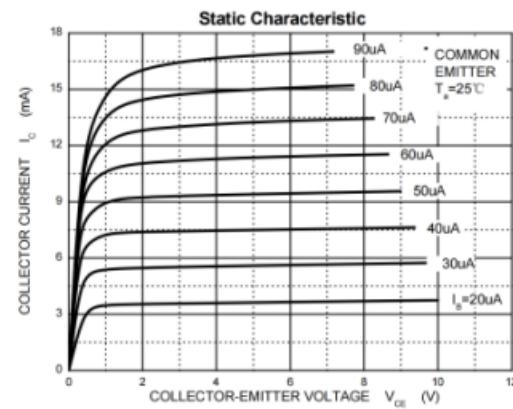
Parameter	Symbol	Testconditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{CBO}$	$I_c = 100\mu\text{A}, I_E = 0$	180			V
Collector-emitter breakdown voltage *	$V_{CEO}$	$I_c = 1.0 \text{ mA}, I_B = 0$	160			V
Emitter-base breakdown voltage	$V_{EBO}$	$I_E = 10\mu\text{A}, I_c = 0$	6			V
Collector cutoff current	$I_{CBO}$	$V_{CB} = 120\text{V}, I_E = 0$		50		nA
Emitter cutoff current	$I_{EBO}$	$V_{EB} = 4.0\text{V}, I_c = 0$		50		nA
DC current gain *	$h_{FE}$	$I_c = 1.0 \text{ mA}, V_{CE} = 5 \text{ V}$	80			
		$I_c = 10 \text{ mA}, V_{CE} = 5 \text{ V}$	100		300	
		$I_c = 50 \text{ mA}, V_{CE} = 5 \text{ V}$	50			
Collector-emitter saturation voltage *	$V_{CE(sat)}$	$I_c = 50 \text{ mA}, I_B = 5.0 \text{ mA}$		0.5		V
Base-emitter saturation voltage *	$V_{BE(sat)}$	$I_c = 50 \text{ mA}, I_B = 5.0 \text{ mA}$		1.0		V
Transistor frequency	$f_T$	$V_{CE} = 10\text{V}, I_c = 10\text{mA}, f = 100\text{MHz}$	100			MHz

\* Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle=2.0%.

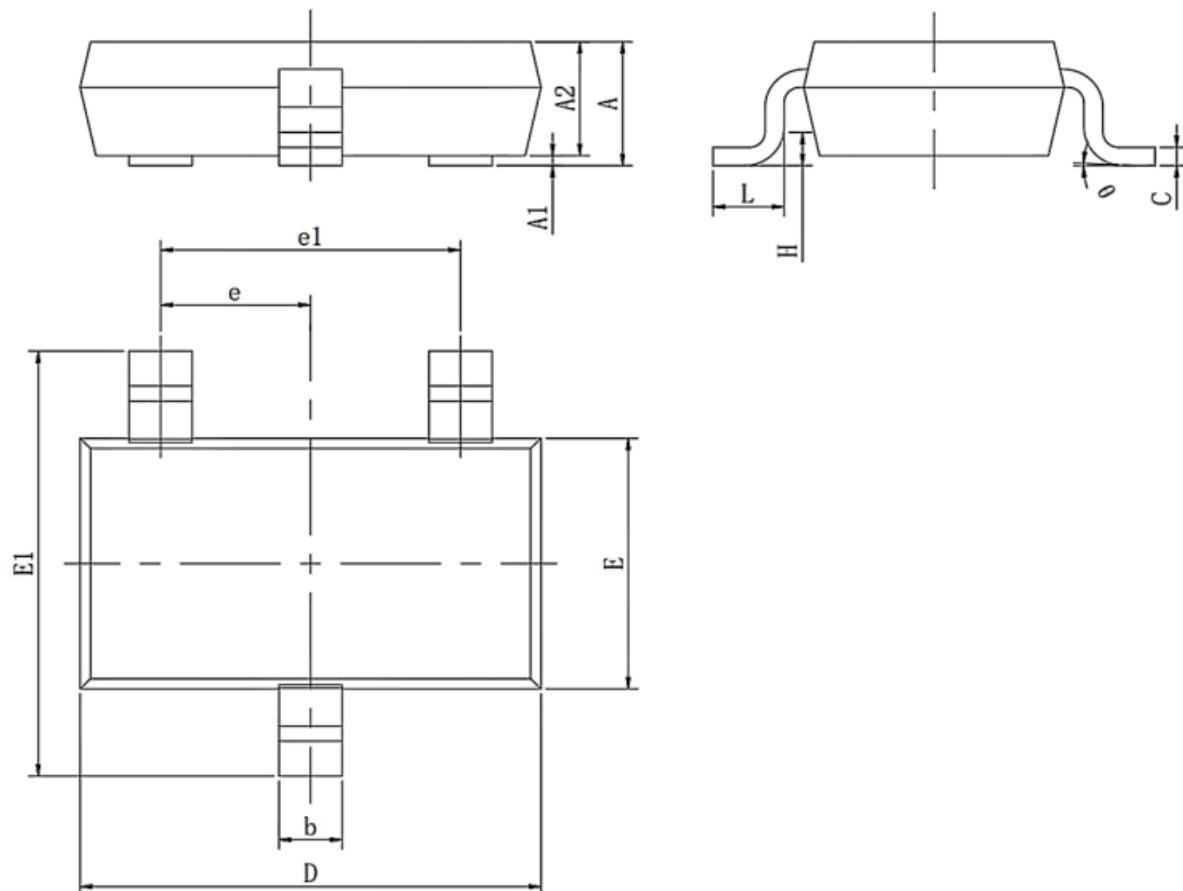
## Classification of $h_{FE}$ (2)

Type	MMBT5551
Range	100-300

## Typical Characteristics



## Outline Dimensions

**SOT-23**
**Unit : mm**


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
C	0.080	0.200	0.003	0.008
D	2.800	3.020	0.110	0.119
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.95 (BSC)		0.037(BSC)	
e1	1.90 (BSC)		0.075(BSC)	
L	0.300	0.500	0.012	0.020
$\theta$	0°	8°	0°	8°

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